

T-46-23-12

Ordering number: EN2361

CMOS LSI

| | |
|--------------|--|
| SANYO | LC3517A, AM, AS, AL, AML, ASL |
| | 2048-word × 8-bit CMOS Static RAM |

OVERVIEW

LC3517A series devices are silicon-gate CMOS, static RAM ICs configured as 2048 words × 8 bits. They incorporate an output enable for high-speed memory access, and TTL-compatible, tristate outputs for direct interfacing with a bus.

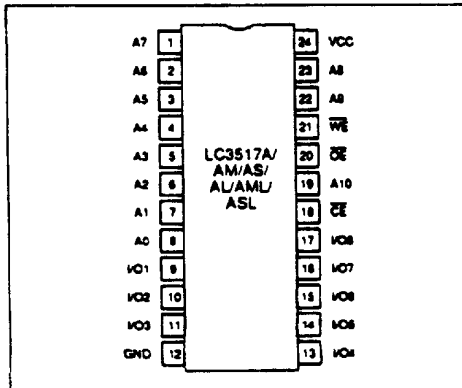
LC3517A series ICs feature a data retention mode and a low standby current, making them ideal for low-power or battery-powered equipment. In particular, the LC3517AL, LC3517AML and LC3517ASL offer a guaranteed maximum standby current of 1 µA at 60 deg. C.

LC3517A series ICs operate from a 5 V supply and are available in 24-pin DIPs, 24-pin MFPs and 24-pin SDIPs.

FEATURES

- 100 ns (LC3517A-10 series), 120 ns (LC3517A-12 series) and 150 ns (LC3517A-15 series) maximum address access times
- 0.2 µA at 25 deg. C and 1.0 µA at 60 deg. C (LC3517AL/AML/ASL-10/12/15), and 5.0 µA at 60 deg. C and 30 µA at 85 deg. C (LC3517A/AM/AS-10/12/15) maximum standby currents
- 55 mA maximum supply current at f = 1 MHz
- Data retention for V_{CC} = 2.0 to 5.5 V
- Asynchronous operation
- TTL-compatible, tristate input/outputs
- Single 5 V supply
- 24-pin DIP, 24-pin MFP and 24-pin SDIP

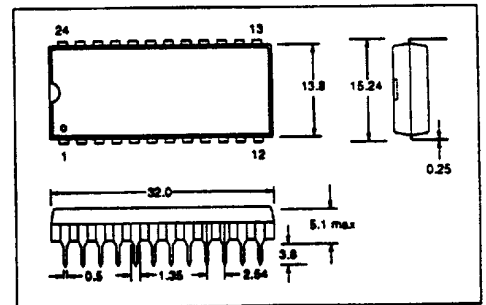
PINOUT



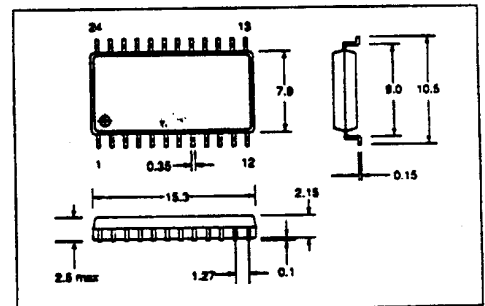
PACKAGE DIMENSIONS

Unit: mm

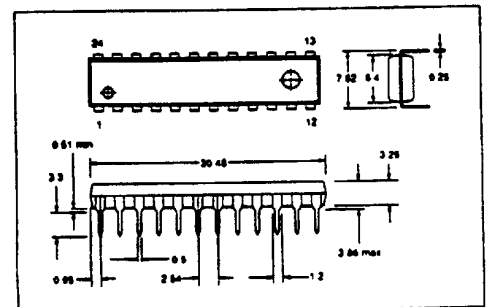
3072-DIP24NS (LC3517A/AL)



3045B-MFP24 (LC3517AM/AML)



3092-DIP24SNS 300 mil (LC3517AS/ASL)

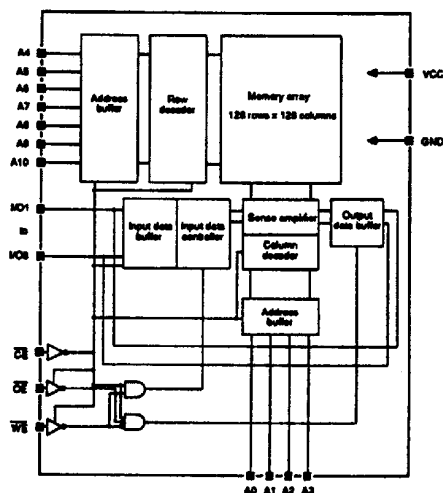


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BLOCK DIAGRAM



PIN DESCRIPTION

| Number | Name | Description |
|--------------------|-----------------|-------------------------|
| 1 to 8, 19, 22, 23 | A0 to A10 | Address inputs |
| 9 to 11, 13 to 17 | I/O1 to I/O8 | Data inputs/outputs |
| 12 | GND | Ground |
| 18 | \overline{CE} | Chip enable input |
| 20 | \overline{OE} | Output enable input |
| 21 | \overline{WE} | Read/write select input |
| 24 | VCC | 5 V supply |

SPECIFICATIONS

Absolute Maximum Ratings

| Parameter | Symbol | Rating | Unit |
|-----------------------------|----------------------|------------------------|--------|
| Supply voltage | $V_{CC \text{ max}}$ | 7.0 | V |
| Input voltage range | V_{IH} | -0.5 to $V_{CC} + 0.5$ | V |
| Input/output voltage range | V_{IO} | -0.5 to $V_{CC} + 0.5$ | V |
| Operating temperature range | T_{opg} | -30 to 85 | deg. C |
| Storage temperature range | T_{stg} | -55 to 125 | deg. C |

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Recommended Operating Conditions

T_a = 25 deg. C

| Parameter | Symbol | Rating | Unit |
|----------------------|--------------------|------------|------|
| Supply voltage | V _{CC} | 5.0 | V |
| Supply voltage range | V _{CC} op | 4.5 to 5.5 | V |

Electrical Characteristics

V_{CC} = 5 V ±10%, T_a = -30 to 85 deg. C unless otherwise noted

| Parameter | Symbol | Condition | Rating | | | Unit | |
|------------------------------|-------------------|---|----------------------------|-----|-----------------------|------|----|
| | | | min | typ | max | | |
| Quiescent supply current | I _{CCQ1} | V _{CE} = 0 V, V _{IN} = V _{CC} or GND, I _{VO} = 0 mA | - | 30 | 55 | mA | |
| | | V _{CE} = V _{IL} , V _{IN} = V _{IH} or V _{IL} , I _{VO} = 0 mA | - | 40 | 70 | | |
| Average supply current | I _{CCQ2} | Minimum cycle time, duty = 100%, I _{VO} = 0 mA | - | 50 | 80 | mA | |
| Standby supply current | I _{CCS} | V _{CE} = V _{CC} - 0.2 V, V _{IN} = 0 V to V _{CC} . See note 1. | T _a = 60 deg. C | - | - | 5.0 | μA |
| | | | T _a = 85 deg. C | - | - | 30 | |
| | | V _{CE} = V _{CC} - 0.2 V, V _{IN} = 0 V to V _{CC} . See note 2. | T _a = 25 deg. C | - | - | 0.2 | |
| | | | T _a = 60 deg. C | - | - | 1.0 | |
| | | V _{CE} = V _{IL} , V _{IN} = 0 V to V _{CC} | - | 1.0 | 3.0 | mA | |
| LOW-level input voltage | V _{IL} | | -0.3 | - | 0.8 | V | |
| HIGH-level input voltage | V _{IH} | | 2.2 | - | V _{CC} + 0.3 | V | |
| LOW-level output voltage | V _{OL} | I _{OL} = 2.0 mA | - | - | 0.4 | V | |
| HIGH-level output voltage | V _{OH} | I _{OH} = -1.0 mA | 2.4 | - | - | V | |
| Input capacitance | C _{IN} | V _{IN} = 0 V, f = 1 MHz, T _a = 25 deg. C | - | - | 5 | pF | |
| Input/output capacitance | C _{VO} | V _{VO} = 0 V, f = 1 MHz, T _a = 25 deg. C | - | - | 10 | pF | |
| Input leakage current | I _I | V _{IN} = 0 to V _{CC} | -1.0 | - | 1.0 | μA | |
| Input/output leakage current | I _{LO} | V _{CE} or V _{SE} = V _{IH} , V _{VO} = 0 V to V _{CC} | -5.0 | - | 5.0 | μA | |

Notes

1. LC3517A/AM/AS-10/12/15
2. LC3517AL/AML/ASL-10/12/15
3. Typical values are measured at V_{CC} = 5.0 V and T_a = 25 deg. C.

Timing Characteristics

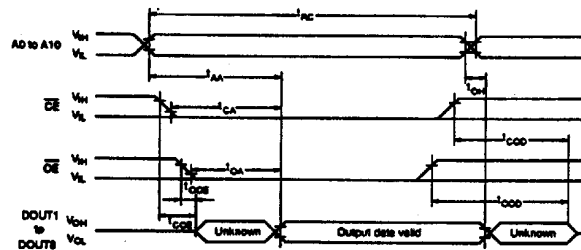
Test conditions

- LOW-level pulse—0.6 V
- HIGH-level pulse—2.4 V
- Input rise and fall times—5 ns
- LOW-level timing reference—V_L = V_{OL} = 0.8 V
- HIGH-level timing reference—V_H = V_{OH} = 2.2 V
- Output load—1 TTL gate + C_L = 100 pF (including jig capacitance)

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Read timing

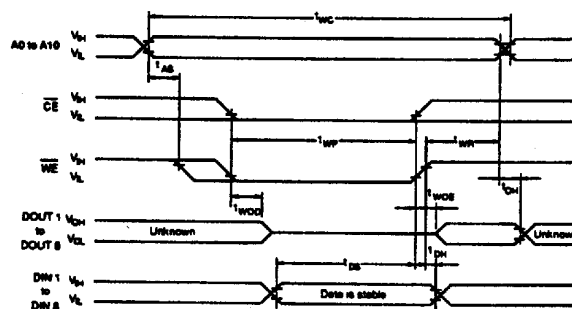


$V_{CC} = 5 V \pm 10\%$, $T_c = -30$ to 85 deg. C

| Parameter | Symbol | LC3517A/AM/AS-10, LC3517AL/AML/ASL-10 | | LC3517A/AM/AS-12, LC3517AL/AML/ASL-12 | | LC3517A/AM/AS-15, LC3517AL/AML/ASL-15 | | Unit |
|----------------------------------|-----------|--|-----|--|-----|--|-----|------|
| | | min | max | min | max | min | max | |
| Read cycle time | t_{AC} | 100 | - | 120 | - | 150 | - | ns |
| Address access time | t_{AA} | - | 100 | - | 120 | - | 150 | ns |
| Output-enable access time | t_{OA} | - | 60 | - | 70 | - | 80 | ns |
| Chip-enable access time | t_{CA} | - | 100 | - | 120 | - | 150 | ns |
| Output hold time | t_{OH} | 5 | - | 5 | - | 5 | - | ns |
| Output-enable propagation delay | t_{OEE} | 5 | - | 5 | - | 5 | - | ns |
| Chip-enable propagation delay | t_{OCE} | 5 | - | 5 | - | 10 | - | ns |
| Output-disable propagation delay | t_{OOD} | - | 35 | - | 40 | - | 50 | ns |
| Chip-disable propagation delay | t_{COO} | - | 35 | - | 40 | - | 50 | ns |

Write timing

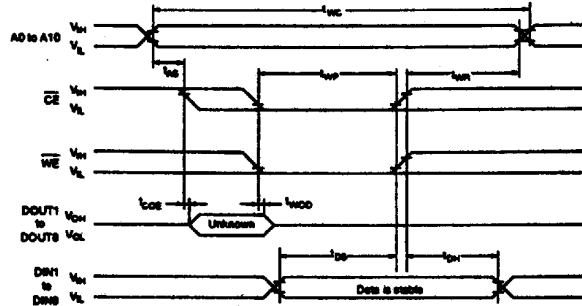
Write cycle 1



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Write cycle 2



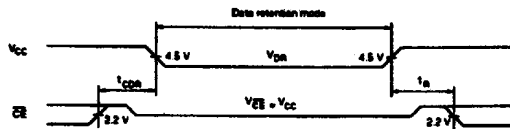
$V_{CC} = 5 V \pm 10\%$, $T_c = -30$ to 85 deg. C

| Parameter | Symbol | LC3517A/AM/AS-10, LC3517AL/AML/ASL-10 | | LC3517A/AM/AS-12, LC3517AL/AML/ASL-12 | | LC3517A/AM/AS-15, LC3517AL/AML/ASL-15 | | Unit |
|---------------------------------|-----------|--|-----|--|-----|--|-----|------|
| | | min | max | min | max | min | max | |
| Write cycle time | t_{WC} | 100 | - | 120 | - | 150 | - | ns |
| Address setup time | t_{AS} | 0 | - | 0 | - | 0 | - | ns |
| Write pulsewidth | t_{WP} | 75 | - | 95 | - | 120 | - | ns |
| Write recovery time | t_{WR} | 10 | - | 10 | - | 10 | - | ns |
| Data setup time | t_{DS} | 50 | - | 60 | - | 70 | - | ns |
| Data hold time | t_{DH} | 0 | - | 0 | - | 0 | - | ns |
| Write-enable propagation delay | t_{WCE} | 5 | - | 5 | - | 5 | - | ns |
| Write-disable propagation delay | t_{WDE} | - | 35 | - | 40 | - | 50 | ns |

Notes

1. Hold \overline{WE} HIGH during the read cycle.
2. Do not apply opposite phase signals to DOUT when it is connected to the output bus.
3. t_{WP} can be measured when \overline{CE} and \overline{WE} are LOW.
4. t_{WR} , t_{DS} and t_{DH} are measured from the time when \overline{CE} or \overline{WE} goes HIGH.
5. DOUT becomes high impedance after either \overline{CE} or \overline{OE} goes HIGH, or \overline{WE} goes LOW.
6. t_{AS} can be measured when \overline{CE} and \overline{WE} go LOW.
7. DOUT is high impedance when \overline{OE} is HIGH during the write cycle.
8. DOUT has the same phase as the data to be written during the write cycle.
9. DOUT holds the data readout from the next address.

Data Retention Characteristics



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T_a = -30 to 85 deg. C

| Parameter | Symbol | Condition | Rating | | | Unit | |
|------------------------------------|-------------------|--|----------------------------|-----|-----|------|----|
| | | | min | typ | max | | |
| Data retention mode supply voltage | V _{DR} | V _{EE} = V _{CC} , V _{IN} = 0 V to V _{CC} | 2.0 | - | 5.5 | V | |
| Data retention mode supply current | I _{CCDR} | V _{EE} = V _{CC} , V _{CC} = 3.0 V, V _{IN} = 0 V to V _{CC} . See note 1. | T _a = 60 deg. C | - | - | 4.0 | μA |
| | | | T _a = 85 deg. C | - | - | 20 | |
| | | V _{EE} = V _{CC} , V _{CC} = 3.0 V, V _{IN} = 0 V to V _{CC} . See note 2. | T _a = 25 deg. C | - | - | 0.2 | |
| | | | T _a = 60 deg. C | - | - | 1.0 | |
| Chip-enable setup time | t _{CS} | | 0 | - | - | ns | |
| Chip-enable hold time | t _H | | t _{CH} | - | - | ns | |

Notes

1. LC3517A/AM/AS-10/12/15
2. LC3517AL/AML/ASL-10/12/15

Mode Selection

| Mode | \overline{CE} | \overline{OE} | \overline{WE} | Input/output | Supply current |
|----------------|-----------------|-----------------|-----------------|----------------|------------------|
| Reset cycle | L | L | H | Data output | I _{CCA} |
| Write cycle | L | X | L | Data input | I _{CCA} |
| Output disable | L | H | X | High impedance | I _{CCA} |
| Standby | H | X | X | High impedance | I _{CCS} |

Note

X = don't care

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